

1 **Tribology of Retaining Rings in Chemical**
2 **Mechanical Planarization**

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9 Stribeck and Stribeck+ curves helped determine the tribological
10 mechanisms in the ring-slurry-pad interface. Both methods gave consistent
11 results with the lubrication mechanism starting at “boundary lubrication”
12 and transitioning to “mixed lubrication” as pseudo-Sommerfeld numbers
13 increased. COF for PPS rings were higher than PEEK. They were also
14 higher for inter-level dielectric (ILD) processes as compared to copper.
15 Stribeck curves were used to infer wear rate information about the ring,
16 which in conjunction with Stribeck+ curves could help choose process
17 parameters that balanced wafer removal with ring wear. Data cluster shapes
18 were shown to be due to shear and normal force fluctuations.

19
20 **Introduction** – In CMP, a chemically-rich slurry containing abrasive nanoparticles is first
21 delivered to the pad surface and allowed to form a thin film across the surface of the
22 rotating polishing pad. A patterned wafer, having some gross topography, is then inserted
23 within a carrier and held in place by a plastic retaining ring containing slots on its periphery

24 for slurry access into the pad-wafer interface. The wafer and retaining ring assembly are
25 then pressed face down against the pad which itself contains many surface asperities as
26 well as deep grooves. Over time, a combination of chemical and mechanical effects remove
27 the “up-features” of the wafer thereby resulting in local and global planarization of the
28 workpiece.

29

30 One of the more effective methods for understanding CMP fundamentals, especially when
31 it comes to the mechanical effects involved, is through tribological studies where the
32 objective is to exploit frictional forces to remove a certain amount of material from the
33 wafer while ensuring that the same forces are low enough to extend the useful life of the
34 ring as well as the pad. Our research team has successfully shown the utility of traditional
35 Stribeck curves in determining the lubrication mechanisms involved in the pad-slurry-
36 wafer interface in CMP [1-3]. In our recent works, [4-6] we have also introduced a new
37 method for determining an “improved” Stribeck curve (which we have called the
38 “Stribeck+ curve”) that has yielded more useful tribological information while
39 dramatically reducing consumables as well as experimental time compared to the
40 traditional means. The key point that we have emphasized in our work is that the Stribeck+
41 curve does not assume normal force to be constant throughout the polishing process as we
42 can measure it, as well as the shear force, instantaneously.

43

44 We believe that it would be highly beneficial if we could determine whether the utility of
45 the Stribeck+ curve can be extended to retaining rings. This would help process engineers,
46 tool makers and consumables suppliers to better understand the tribology within a given

47 set of consumables, at certain process conditions, and aim to process robustness as well as
48 increase ring life without compromising wafer removal rate. Here, we set out to
49 tribologically test identically shaped broken-in PPS and PEEK rings having 18 equidistant
50 peripheral slots (3-mm in width and depth), using copper and ILD slurries at various
51 pressures and velocities to determine whether we can attain the above objectives.

52

53 ***Experimental Apparatus and Procedure*** – All tests were done on an Araca APD-800
54 polisher and tribometer equipped with proprietary force transducers suitable for acquiring
55 real-time shear and normal force at high (i.e. up to 1,600 Hz) frequencies [7]. Attached to
56 the carrier head (needed to polish our 300 mm wafers) was an interface template with a
57 retaining ring and backing film assembly. To isolate the COF in the ring-slurry-pad
58 interface, the polishing process was performed without a wafer. Prior to polishing and data
59 acquisition, a new CMC D100 concentrically grooved pad was broken in for 30 mins with
60 deionized water using a 3M A165 diamond disc at a normal load of 44.5 N, a rotation rate
61 of 95 RPM and a sweep frequency of 0.17 Hz. The same recipe was used for the *in-situ*
62 conditioning during ring polishing. The ILD and copper slurries employed were Fujimi
63 PL-4217 and PL-7106, respectively. Both slurries contained silica-based nano-particles
64 and were pre-diluted as per the manufacturer’s specifications. In all cases, the slurry
65 flowrate was 200 ml per min. For generating the Stribeck+ curves, we performed only one
66 3-minute polishing run with a multitude of gradual yet continuous changes (e.g. time-
67 dependent ramp-ups and ramp-downs) in polishing pressure and sliding velocity. During
68 each 3-minute run, normal forces and shear forces were instantaneously measured at 1,000
69 Hz. Table I shows the conditions for each step involved in constructing the Stribeck+ curve.

70 Each ramp-up or ramp-down step took approximately 2 seconds. The same pressure and
71 velocity combinations were used to carry out the discrete runs needed to construct each
72 Stribeck curve.

73

74 **Results and Discussions** – Fig. 1 shows the traditional Stribeck curves (circular symbols)
75 corresponding to the PPS ring using both copper (red) and ILD (green) slurries. In each
76 case, the 5 data points represent average COF values obtained from individual 2-minute
77 polishes at a given pressure-velocity combination as per Table 1. Fig. 1 also shows the
78 Stribeck+ curves (dots) corresponding to the same polishing conditions. For purposes of
79 comparison, the 5 data points are superimposed on the 180,000 Stribeck+ data points
80 obtained by a single run through multiple pressures, velocities and slurries (copper slurry
81 in orange, and ILD slurry in black). For the copper slurry, the traditional Stribeck curve
82 starts off in “boundary lubrication” with an average COF of about 0.44, and then begins to
83 slightly transition into “mixed lubrication” half-way through where average COF drops to
84 0.36. The same trend is evident for the ILD slurry with 0.65 as the starting average COF
85 value which then drops to 0.50 at higher pseudo-Sommerfeld numbers. It is clear that, with
86 a single run, Fig. 1 is able to capture all of the trends seen in the individual Stribeck curve
87 data points, and also provide additional valuable information as follows:

88

- 89 • The Stribeck+ curve, being continuous in nature, indicates that anomalous
90 tribological behavior does not exist in between discrete polishing conditions.
- 91 • A fascinating commonality becomes evident in the evolution of the shape of data
92 clusters as a function of pseudo-Sommerfeld number which is not just a visual
93 artifact due to the log-log nature of the graph. Here, the ratio of measured variances

94 in shear force to those of normal force depend strongly on the pseudo-Sommerfeld
95 number. We believe this to be a fundamental aspect of CMP that has so far been
96 overlooked by the CMP community. We plan to report on it soon.

97 • As seen in the inset diagram in Fig. 1, the data points in each Stribeck+ curve can
98 be replotted with the y-axis representing $\text{COF} \times P \times v$ which we can assume to be
99 proportional to the instantaneous wear rate of the retaining ring from a purely
100 mechanical standpoint [8]. The notion of obtaining an indicator for instantaneous
101 wear rate (or removal rate) from a single 3-min run can be quite powerful and
102 revolutionary. This is a new idea and one that will require further study to be
103 confirmed. Of course, in CMP, a particular pressure and velocity combination gets
104 selected to cause a desired removal and planarization rate on the wafer surface, and
105 not necessarily to reduce ring wear. However, given the fact that, in high-volume
106 manufacturing, the pressure applied to a product wafer is always lower by 1 or 2
107 PSI than the ring pressure, we believe that our new way of combining the
108 tribological and implied ring wear (or wafer removal) rate plots can help process
109 engineers select desired operating conditions based on their main sets of objectives
110 having to do with planarization rate, wafer throughput and consumables wear.

111

112 By way of another example, we performed tests at the same conditions using a retaining
113 ring made of a different material (polyether ether ketone, PEEK) which had the same size
114 and geometry as that of the PPS ring. Over the years, PEEK has emerged as an alternative
115 to PPS for constructing retaining rings. This is due to various reasons such as less shedding,
116 higher wear-resistance, lower COF and lower operating temperature during CMP. Fig. 2,

117 confirms that similar trends exist in the case of the PEEK ring when it comes to Stribeck
118 and Stribeck+ curves, as well as the implied kinetic curve shown in the inset diagram. In
119 Fig. 2, it must be noted that, for a yet to be determined reason, the superimposition does
120 not work as well as that in Fig. 1 as the individual runs associated with the Stribeck curve
121 of Fig. 2 are not always centered inside the respective data clusters of the Stribeck+ curves.

122

123 Both figures indicate that COF values for the PPS ring are on average 21 percent higher
124 than PEEK. The higher values are consistent with earlier findings by other researchers [9].
125 Average COF values are also higher by 55 percent for ILD processes as compared to copper.
126 This is likely due to the higher abrasive content of the ILD slurry (10% by weight) as
127 compared to less than 1% for the copper slurry. Average pad surface temperature for the
128 PPS ring is 9 to 11 °C higher than that of PEEK. Also, in all cases, pad temperature is
129 higher by 2 to 3 °C when the ILD slurry is used as compared to the copper slurry. These
130 temperature differences are quite consistent with, and a result of, their corresponding COF
131 values.

132

133 **Conclusions** – We utilized Stribeck and Stribeck+ curves to tribologically characterize
134 PEEK and PPS retaining rings for copper and ILD CMP. Both methods led us to the same
135 set of conclusions: for a given slurry type COF values for PPS were always higher than for
136 PEEK, and the same relationship held for ILD processes as compared to copper. Pad
137 temperature measurements also corroborated the above finding. Stribeck+ curves were
138 used to construct new kinetic curves which inferred wear rate information about the ring.
139 This information, when used in conjunction with Stribeck+ curves can help identify process

140 parameters that balance wafer removal rate with ring wear rate at a given tribological state.
141 In all cases, a fascinating commonality was seen in the evolution of the shape of data
142 clusters as a function of pseudo-Sommerfeld number indicating the presence of a complex
143 interplay between variances in normal and shear force which will be a subject of our next
144 study.

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146 **References**

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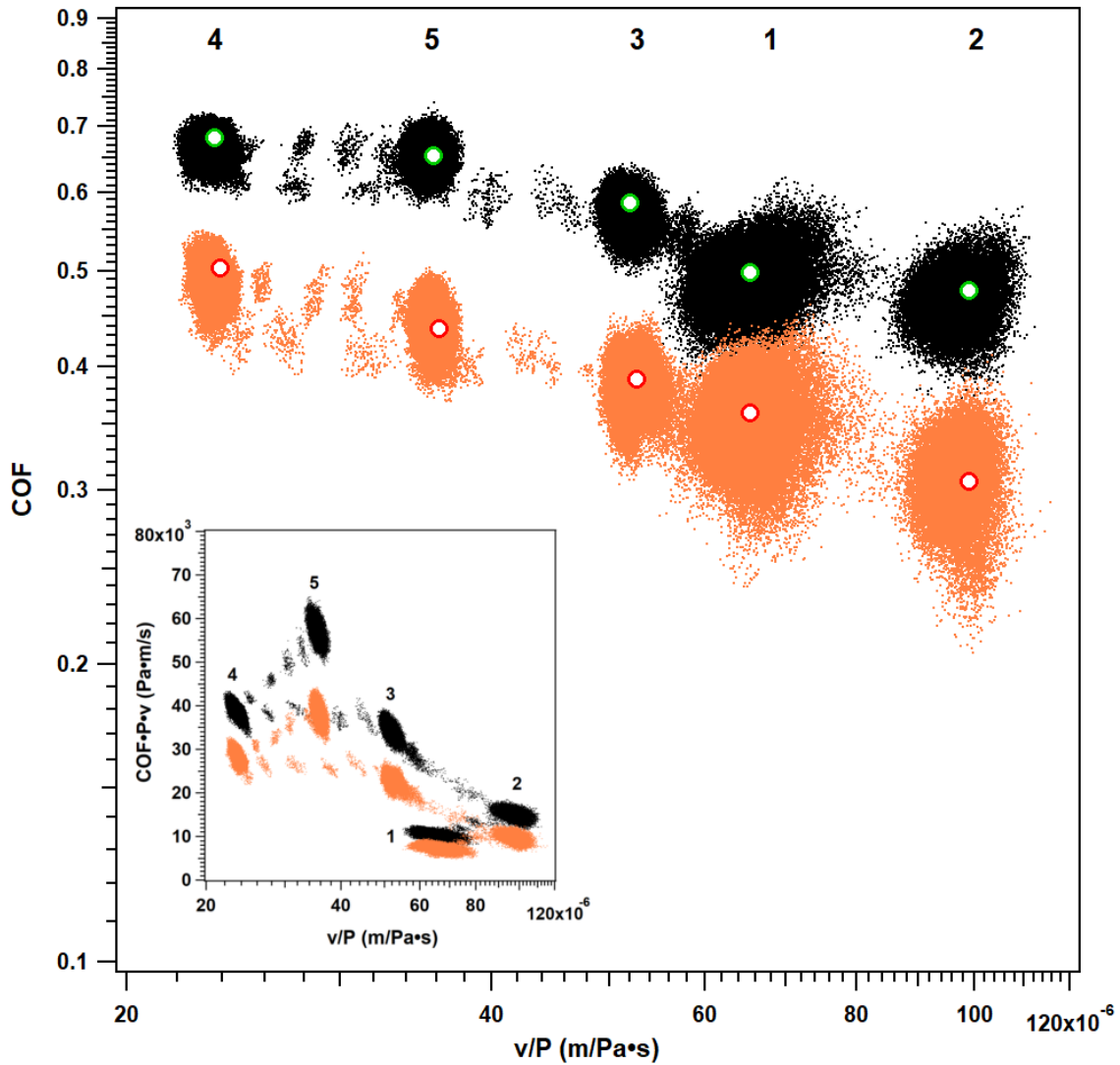
Table I. Experimental conditions for Stribeck and Stribeck+ curves.

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Stribeck+ Step No.	Duration of the Stribeck+ Step (sec)	Pressure (PSI)	Sliding Velocity (m/s)
1	60	2	1.2
2	30	2	1.8
3	30	4	1.8
4	30	6	1.2
5	30	6	1.8

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170 **Fig 1.** Stribeck (open circles) and Stribeck+ (clusters) curves corresponding to the PPS ring

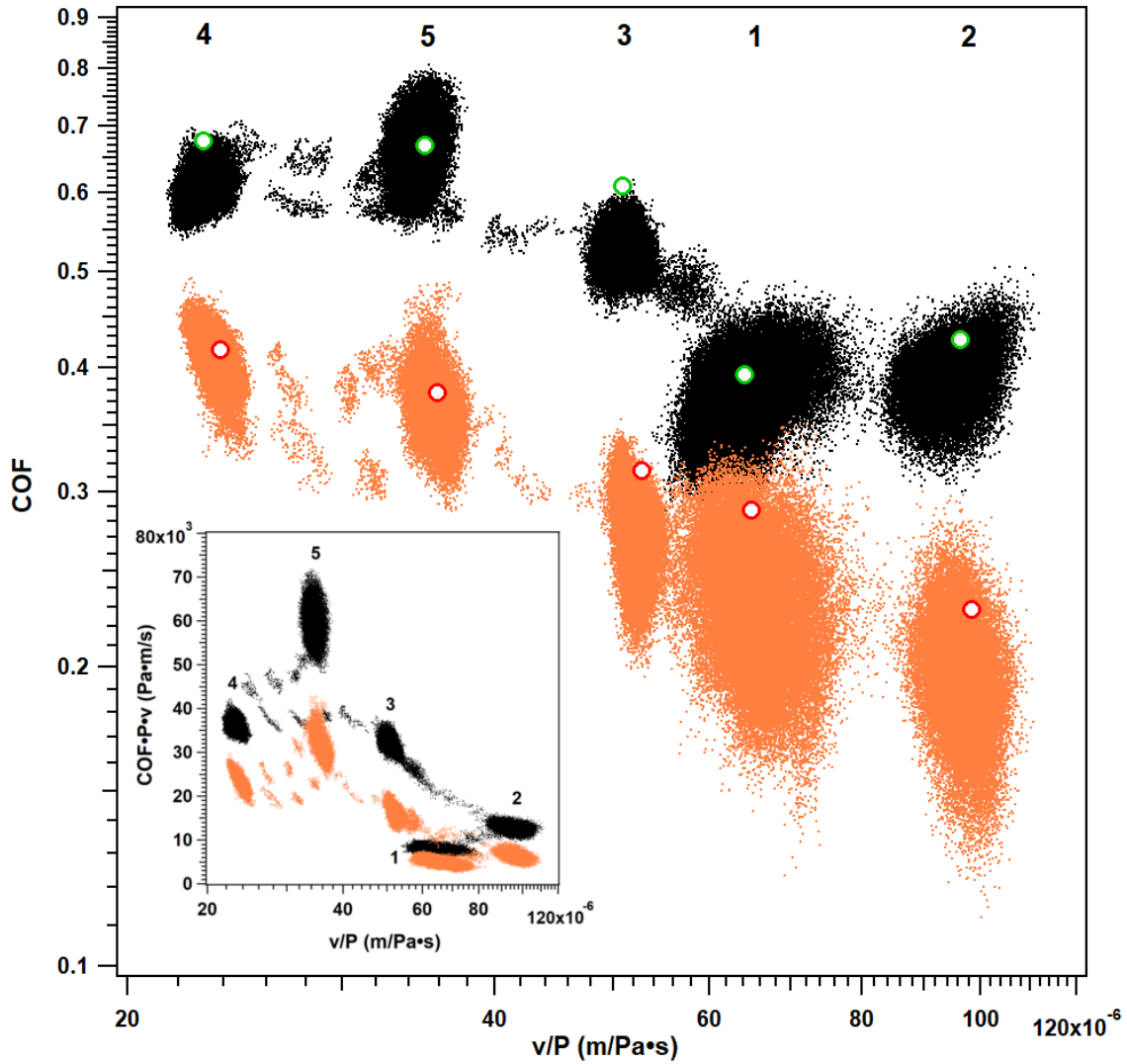
171 using PL-4217 (black) and PL-7106 (orange).

172 Numbers correspond to step numbers in Table 1.

173 Inset: Implied ring wear rate as a function of pseudo-Sommerfeld number

174 for PL-4217 (black) and PL-7106 (orange).

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Fig 2. Stribeck (open circles) and Stribeck+ (clusters) curves corresponding to the PEEK ring using PL-4217 (black) and PL-7106 (orange). Numbers correspond to step numbers in Table 1. Inset: Implied ring wear rate as a function of pseudo-Sommerfeld number for PL-4217 (black) and PL-7106 (orange).